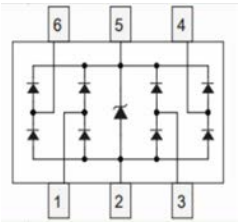
HCEST363LC5VU
ESD PROTECTION DIODE

Discription

The HCEST363LC5VU is a 5-channel ultra low capacitance rail clamp ESD protection diodes array. Each channel consists of a pair of ESD diodes that steer positive or negative ESD current to either the positive or negative rail.A zener diode is integrated in to the array between the positive and negative supply rails.In the typical applications, the negative rail pin (assigned as GND) is connected with system ground. The Positive ESD current is steered to the ground through an ESD diode and Zener diode and the positive ESD voltage is clamped to the zener voltage.

SOT-363



Circuit Diagram

Features

★ 5 channels of ESD protection
★ Provides ESD protectionto IEC61000-4-2 level 4
- ±27kV air discharge
- ±15kV contact discharge
★ Low clampingvoltage
★ Low operating voltage
★ Improved zener structure
★ Optimized package for easyhigh speed data lines PCB layout
★ RoHS compliant

Orderingin formation

Product ID	Pack	Qty(PCS)
HCEST363LC5VU	SOT-363	3000

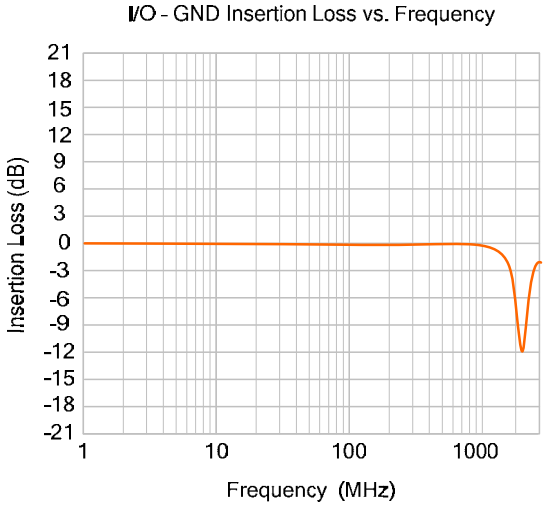
Absolute Ratings(Tamb = 25°C)

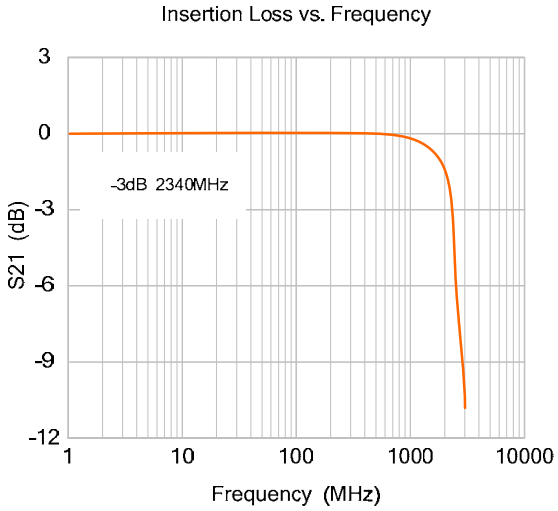
Characteristics	Symbol	Ratings	Unit
Peak Pulse Power(8/20μs)	P_{PP}	55	W
Peak Pulse Current(8/20μs)	I_{PP}	4	A
ESD per IEC 61000-4-2(Air)	V_{ESD1}	±20kV	kV
ESD per IEC 61000-4-2(Contact)	V_{ESD2}	±15kV	kV
Operating Temperature Range	Topr	-55 ~ +125	°C
Storage Temperature Range	Tstg	-55 ~ +150	°C

Electrical Characteristics (Tamb=25°C)

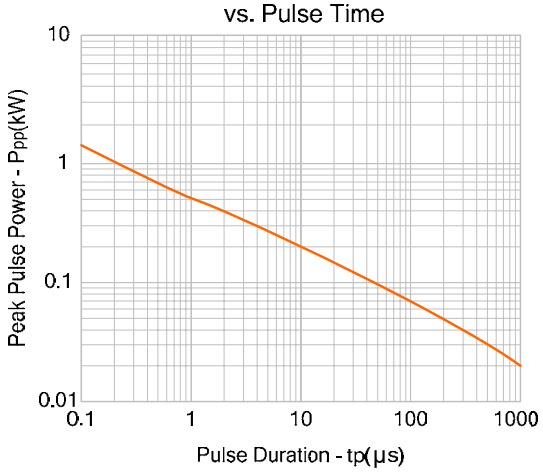
Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
Reverse Working Voltage	V_{RWM}	Any I/O pin to GND			5	V
Reverse Breakdown Voltage	V_{BR}	I_t=1mA; Any I/O pin to GND	6			V
Reverse Leakage Current	I_R	V_{RWM} =5V, T=25°C; Any I/O pin to GND			1	μA
Positive Clamping Voltage	V_{C1}	I_{PP}=1A, t_P=8/20μs; Positive pulse; Any I/O pin to GND			13.0	V
Negative Clamping Voltage	V_{C2}	I_{PP}=1A, t_P=8/20μs; Negative pulse; Any I/O pin to GND		1.8		V
Junction Capacitance Between Channel	C_{J1}	V_R=0V, f=1MHz; Between I/O pins		0.3	0.4	pF
Junction Capacitance Between I/O And GND	C_{J2}	V_R=0V, f=1MHz; Any I/O pin to GND		0.6	0.8	pF

Typical Characteristics

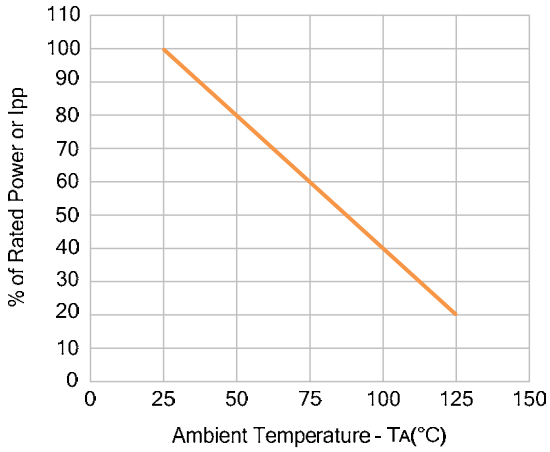




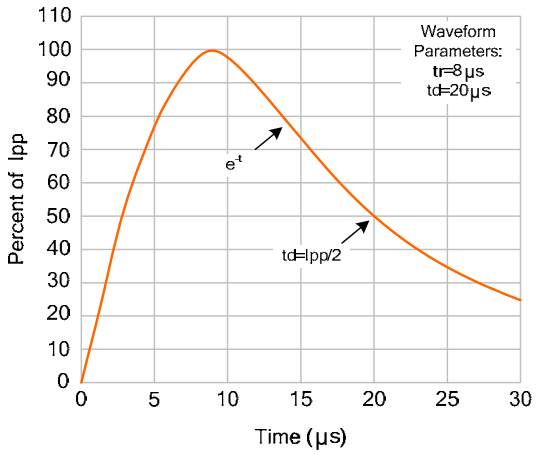
Non-Repetitive Peak Pulse Power vs. Pulse Time



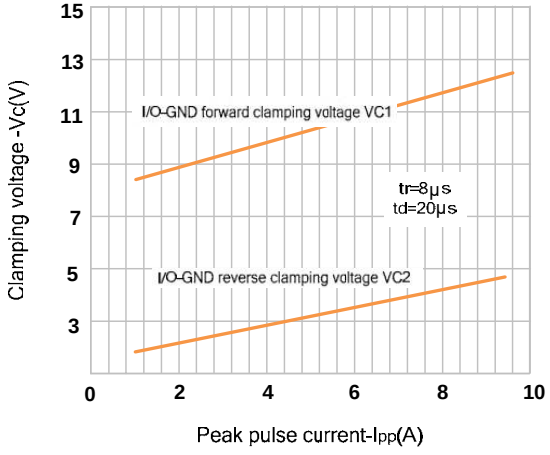
Power Derating Curve



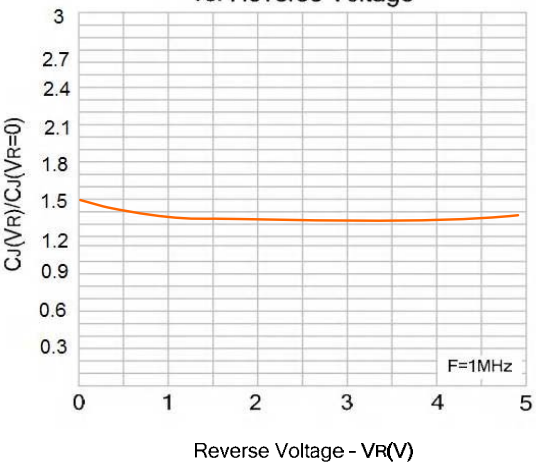
Pulse Waveform



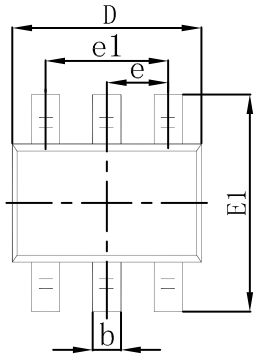
I/O GND clamping voltage vs peak pulse current

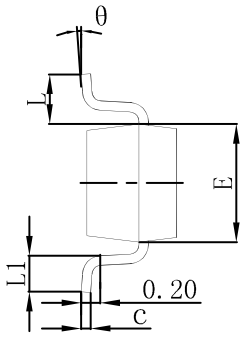


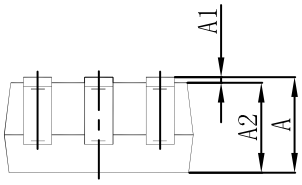
Normalized Capacitance vs. Reverse Voltage



SOT-363 Package Outline Dimensions

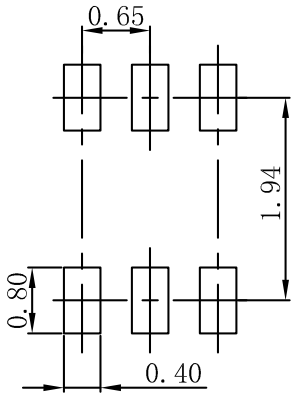






Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.100	0.150	0.004	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.400	0.085	0.094
e	0.650 TYP		0.026 TYP	
e1	1.200	1.400	0.047	0.055
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-363 Suggested Pad Layout



Note:
1.Controlling dimension:in millimeters.
2.General tolerance:± 0.05mm.
3.The pad layout is for reference purposes only.

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